

HA17358B Series

Dual Operational Amplifier

REA03D0001-0100 Rev.1.00 Dec 25, 2006

Description

HA17358B is dual operational amplifiers that provide high gain and internal phase compensation, with single power supply. Operation from split power supply is also possible and the low power supply current drain is independent of the magnitude of the power supply voltages. They can be widely applied to control equipment and to general use.

Features

- Wide range of supply voltage Single supply: 3 V to 36 V, Dual supplies: ± 1.5 V to ± 18 V
- Wide range of common mode voltage, and possible to operate with an input about 0 V, and output around 0 V is W.DZSC.COM available.
- Internally frequency compensated for unity gain.
- Common mode input voltage range includes ground.
- Package outline available in Pb free lead frame: DP-8 SOP-8 (JEITA)

SOP-8 (JEDEC)

Applications

- Battery charger •
- Cordless telephone
- Switching power supply

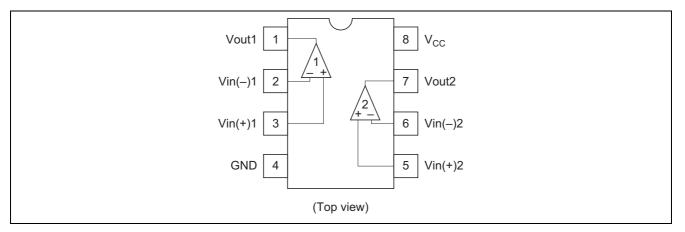
Ordering Information

Application	Package Code (Package Name)
Commercial use	PRDP0008AF-B (DP-8FV)
	PRSP0008DE-B (FP-8DGV)
	PRSP0008DD-C (FP-8DCV)
ed for consumer use and not for automotive.	LA TE WWW.DZSC.COM
	Commercial use

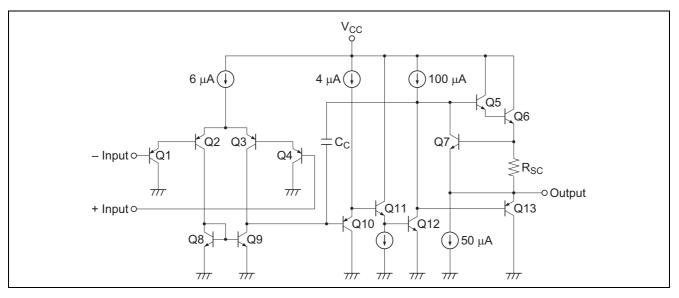


HA17358B Series

Pin Arrangement



Circuit Schematic (1/2)



Absolute Maximum Ratings

					$(Ta = 25^{\circ}C)$
			Ratings		
Item	Symbol	HA17358B	HA17358BF	HA17358BRP	Unit
Supply Voltage	V _{CC}	36	36	36	V
Differential input voltage	V _{IN} (diff)	V _{CC}	V _{cc}	V _{CC}	V
Common mode input voltage	V _{CM}	–0.3 to V_{CC}	-0.3 to V _{CC}	-0.3 to V _{CC}	V
Power dissipation	PT	570 * ¹	385 * ²	385 * ²	mW
Operating temperature	Topr	-40 to +85	-40 to +85	-40 to +85	°C
Storage temperature	Tstg	-55 to +125	-55 to +125	-55 to +125	°C

Notes: 1. This is the allowable value up to $Ta = 55^{\circ}C$. Derate by 8.3 mW/°C above that temperature.

2. These are the allowable values up to Ta = 25°C mounting in air. When it is mounted on glass epoxy board of 40 mm \times 40 mm \times 1.5 mm (t) with 30% wiring density, the allowable value is 570 mW up to Ta = 45°C. If Ta > 45° C, derate by 7.14 mW/°C.

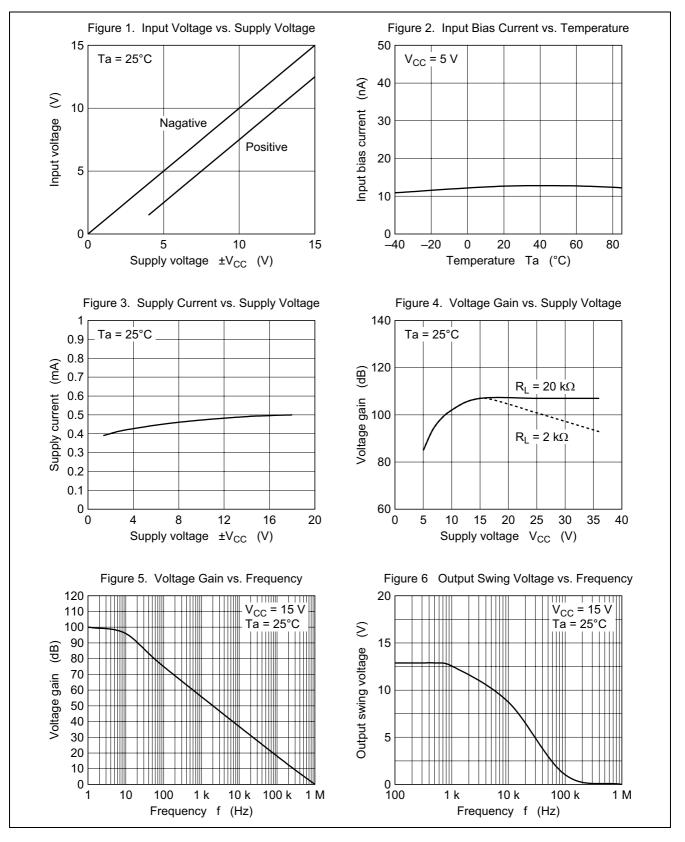
Electrical Characteristics

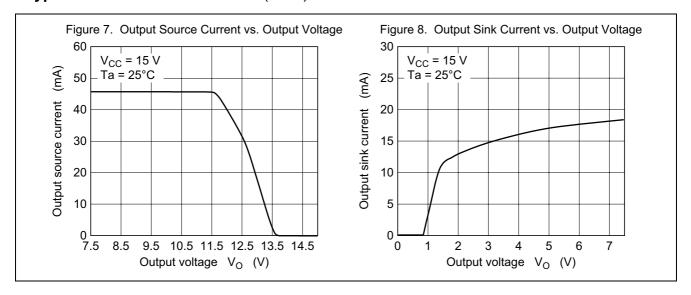
			(Ta = 25°C, V_{CC} = +5 V, unless otherwise specified)			
ltem	Symbol	Min	Тур	Max	Unit	Test Conditions
Input offset voltage	V _{IO}	_	2	5	mV	$V_0 = 1.4 V, R_S = 0 \Omega$
						$V_{CC} = 5 V$ to 30 V
Input offset current	I _{IO}	_	5	30	nA	$V_{CM}=0~V,~I_{IO}=\mid I_{IN(+)}-I_{IN(-)}\mid$
Input bias current	I _{IB}	—	20	200	nA	$V_{CM} = 0 \text{ V}, \text{ I}_{IN(+)} \text{ or } \text{ I}_{IN(-)}$
Power supply rejection ratio	PSRR	_	100	—	dB	$V_{CC} = 5 V \text{ to } 30 V$
Voltage gain	Av	85	100	_	dB	$V_{CC} = 15 \ V, \ R_L \geq 2 \ k\Omega, \label{eq:VCC}$
						$V_0 = 1 V$ to 11 V
Common mode rejection Ratio	CMR	60	70	—	dB	DC, $V_{CM} = 0$ V to ($V_{CC} - 1.5$) V
Common mode input voltage range	V _{IR}	0	_	V _{cc} -1.5	V	V _{CC} = 30 V
Output swing voltage	V _{OH}	26	—	—	V	$V_{CC} = 30 \text{ V}, \text{ R}_{L} = 2 \text{ k}\Omega$
		27	28	_	V	V_{CC} = 30 V, R_L = 10 k Ω
	V _{OL}	_	5	20	mV	$V_{CC} = 5 \text{ V}, \text{ R}_{L} = 10 \text{ k}\Omega$
Output source current	IOSOURCE	20	40	—	mA	$V_{IN(+)} = 1 V, V_{IN(-)} = 0 V,$
						$V_0 = 2 V, V_{CC} = 15 V$
Output sink current	IOSINK	10	15	—	mA	$V_{IN(-)} = 1 V, V_{IN(+)} = 0 V,$
						$V_0 = 2 V, V_{CC} = 15 V$
		12	50	—	μΑ	$V_{IN(-)} = 1 V, V_{IN(+)} = 0 V,$
						$V_0 = 0.2 \text{ V}, V_{CC} = 15 \text{ V}$
Supply current	Icc	_	0.5	1.2	mA	$R_L = \infty$, $V_{CC} = 5 V$
		_	0.7	2	mA	$R_L = \infty$, $V_{CC} = 30 V$
Channel separation	CS	—	-120	—	dB	f = 1 kHz to 20 kHz

Table of Graphs

	Figure	
Input voltage	vs. Supply voltage ±V _{CC}	1
Input bias current	vs. Temperature Ta	2
Supply current	vs. Supply voltage ±V _{CC}	3
Voltage gain	vs. Supply voltage V _{CC}	4
Voltage gain	vs. Frequency f	5
Output swing voltage	vs. Frequency f	6
Output source current	vs. Output voltage V _O	7
Output sink current	vs. Output voltage Vo	8

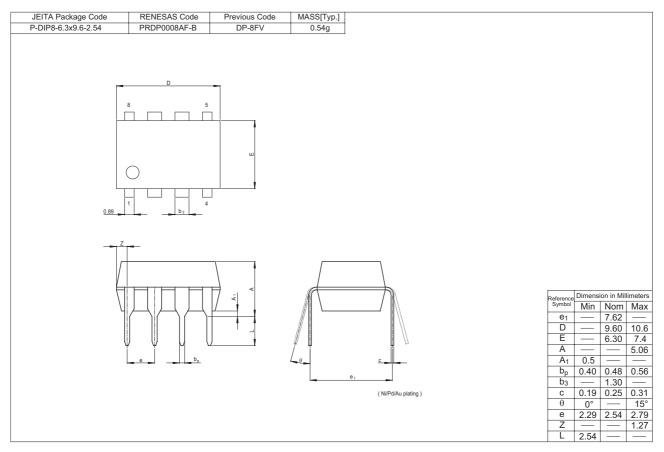
Typical Characteristics Curves

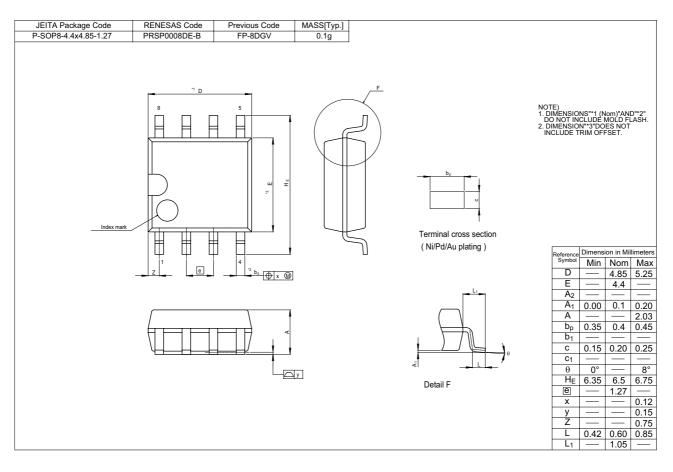




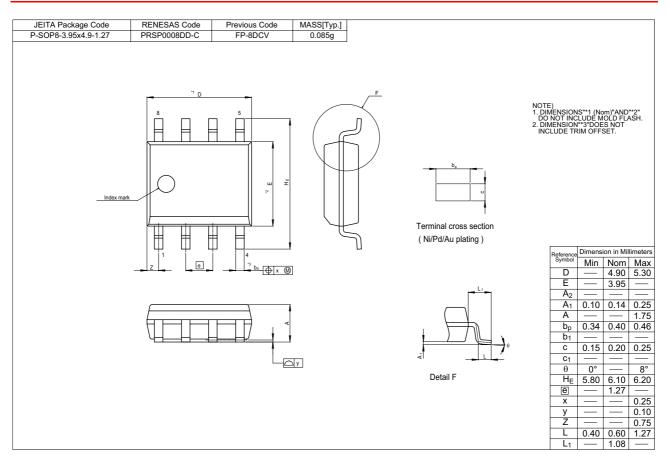
Typical Characteristics Curves (cont.)

Package Dimensions





HA17358B Series



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